



DE LA RECHERCHE À L'INDUSTRIE

Simulation of small polarons with ABINIT using functionalities related to correlated electrons

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- 1 - Reminder: what is a small polaron ?**
- 2 - Computation of a self-trapped small polaron using DFT**
- 3 - Small polaron hopping**

I – Reminder: what is a small polaron ?

- Context: semiconducting/insulating materials
- Introduction of additional charges (electron or holes) coming from point defects
- Different kinds of point defects:

Donors

Liberate electrons

Example:

- **oxygen vacancy** in an insulating oxide
- **cation interstitial** in an insulating oxide
- Single, double ... donor

Number of elementary
charges released

Acceptors

Liberate holes (i.e. catch electrons)

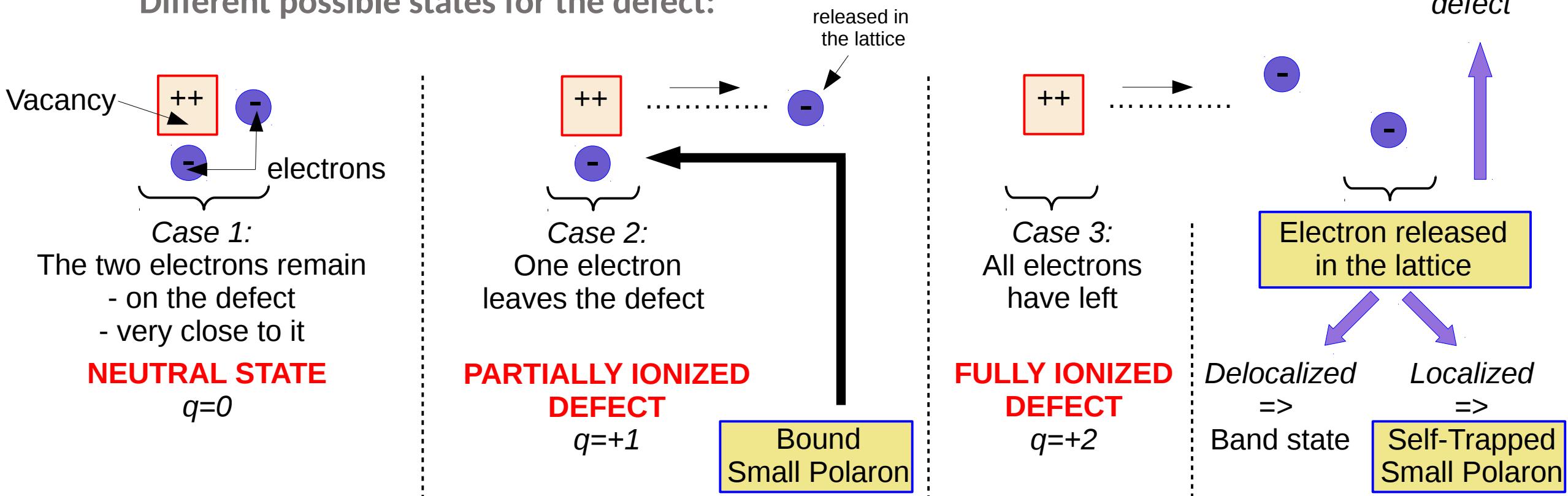
Example:

- **cationic vacancy** in an insulating oxide
- **allovalent substitution of the cation**
(by element of lower valence)

I – Reminder: what is a small polaron ?

- Example: **oxygen vacancy** in oxide = Double Donor

Different possible states for the defect:



- Small polaron = bound or self-trapped
- Depends on the electronic chemical potential μ_e (Fermi level)

Formation energy of the defect:

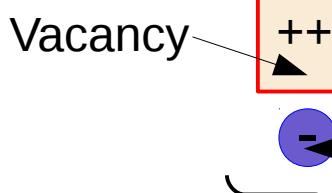
- Examples of different types of defects

- Breaking/reforming bonds
- Interactions between released charges/defect
- Atomic distortions around the defect

$$\Delta E_f = \text{intrinsic cost} + q\mu_e + \sum_i n_i \mu_i$$

Energy of the electron/hole released in the lattice

Energy of the atomic species (i) removed ($n_i > 0$) or added ($n_i < 0$)



Case 1:
The two electrons remain

- on the defect
- very close to it

NEUTRAL STATE

$$q=0$$

Case 2:
One electron leaves the defect

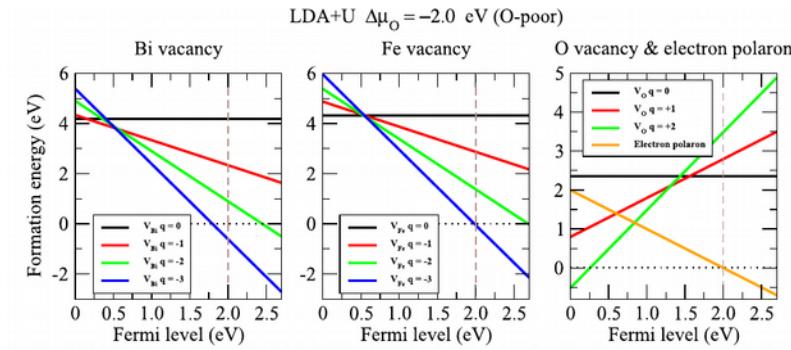
PARTIALLY IONIZED DEFECT

$$q=+1$$

Bound Small Polaron

- Small polaron = bound or self-trapped
- Depends on the electronic chemical potential μ_e (Fermi level)

Ex: vacancies in BiFeO_3



$$\mu_e = E_{\text{VBM}} + \epsilon_F$$

G. Geneste, C. Paillard, B. Dkhil, Phys. Rev. B 99, 024104 (2019)

Case 3:
All electrons have left

FULLY IONIZED DEFECT

$$q=+2$$

Electron released in the lattice

Delocalized
=>
Band state

Localized
=>

Self-Trapped Small Polaron

...
Other polaronic forms

I – Reminder: what is a small polaron ?

Electron released
in the lattice:



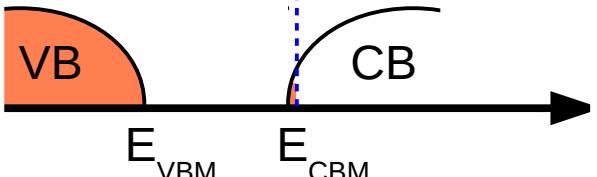
Delocalized
=>
Band state

Localized
=>

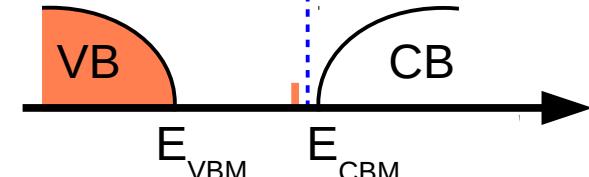
Self-Trapped
Small Polaron
(electron polaron)



Fermi
Level (0K)



Electron in band state
Delocalized throughout the crystal



Electron state detached from CB
Localized in space
Distortions around the localized
charge

Hole released
in the lattice:



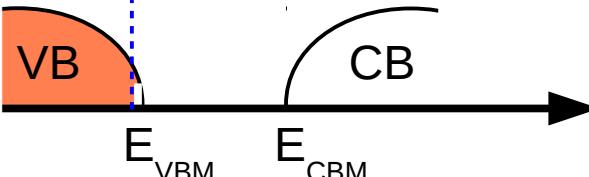
Delocalized
=>
Band state

Localized
=>

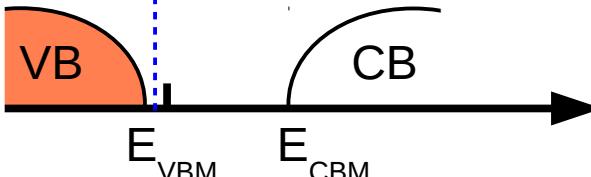
Self-Trapped
Small Polaron
(hole polaron)



Fermi
Level (0K)



Hole in band state
Delocalized throughout the crystal



Hole state detached from VB
Localized in space
Distortions around the localized
charge

I – Reminder: what is a small polaron ?

- How can an excess electron/hole be localized on a single atom in the lattice (“self-trapped”)

To pay:

ZPE associated with quantum confinement

Atomic distortions around (optical phonons)

...

Self-trapping mechanism:

Self-trapping energy (E_{st}) =
Energy difference between total energies of **polaronic configuration** and **delocalized** one.

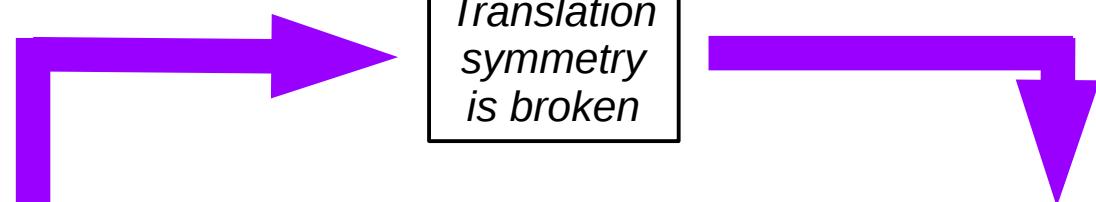
$E_{st} < 0 \Rightarrow$ the **self-trapped polaron is stable**

Can be compensated by:

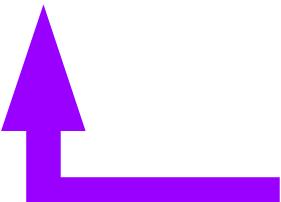
Interaction between the charge and the ~ radial polarization field

...

Translation symmetry is broken

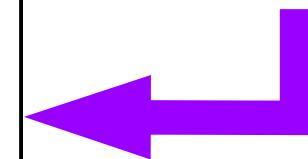


The electron/hole localizes on one site



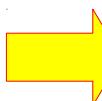
The electronic potential becomes deeper at the site where the electron/hole is localized

Atomic distortions in the neighborhood
“Self-trapping distortion”
(~ radial field of polarization)



II – Computation of a self-trapped small polaron using DFT

- Add/remove electron => keyword **charge (± 1)** (compensated by uniform background)
- XC functional:
 - LDA/GGA: trend to delocalization (self-interaction error);
 - LDA/GGA can be OK for bound polarons, usually not for self-trapped ones;
=> DFT+U (U on atom type/angular momentum concerned by polaron) or Hybrid Functionals with HF (PBE0, HSE06...)
- Rq: oxygen-type hole polarons in oxides => U on oxygen p
- Physical problems encountered:
 - Small polaron alone in supercell
 - Small polaron close to defect, domain wall, etc
 - Small polaron hopping/reorientation
- => How to choose the atom / orbital on which le polaron is localized ?



Choose atom by enforcing atomic distances to 1sr NN may be sufficient

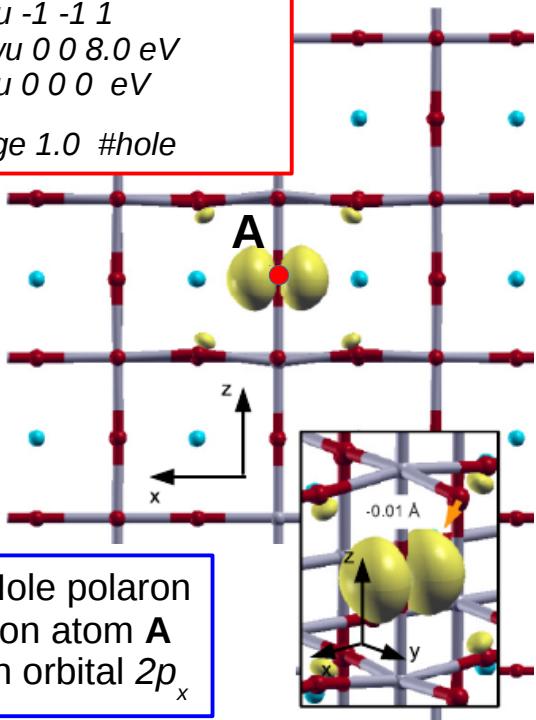
...
But not always to enforce the orbital !

II – Computation of a self-trapped small polaron using DFT

- ABINIT code DFT+U: **occupation matrices** of correlated orbitals
 - Can be constrained over a given number of electronic steps
 - During 1st or all ionic steps
- Two-step procedure to enforce small polaron on given atom in given orbital



```
usepawu 1
znucl 56 50 8 #BaSnO3
lpawu -1 -1 1
upawu 0 0 8.0 eV
jpawu 0 0 0 eV
charge 1.0 #hole
```



(1) Create the ST distortion

- **enforce localization** with occupation matrices, constrained over all electronic steps

```
usedmatpu -30 #neg value: constr over all ionic steps
nstep 30
dmatpawu
...
#atom A
0.8 0.0 0.0
0.0 0.8 0.0
0.0 0.0 0.0 #hole (y,z,x)
...
- structurally optimize
ionmov 2 ntime 100
tolmxf 5.0d-4
#need not to be fully optimized
```

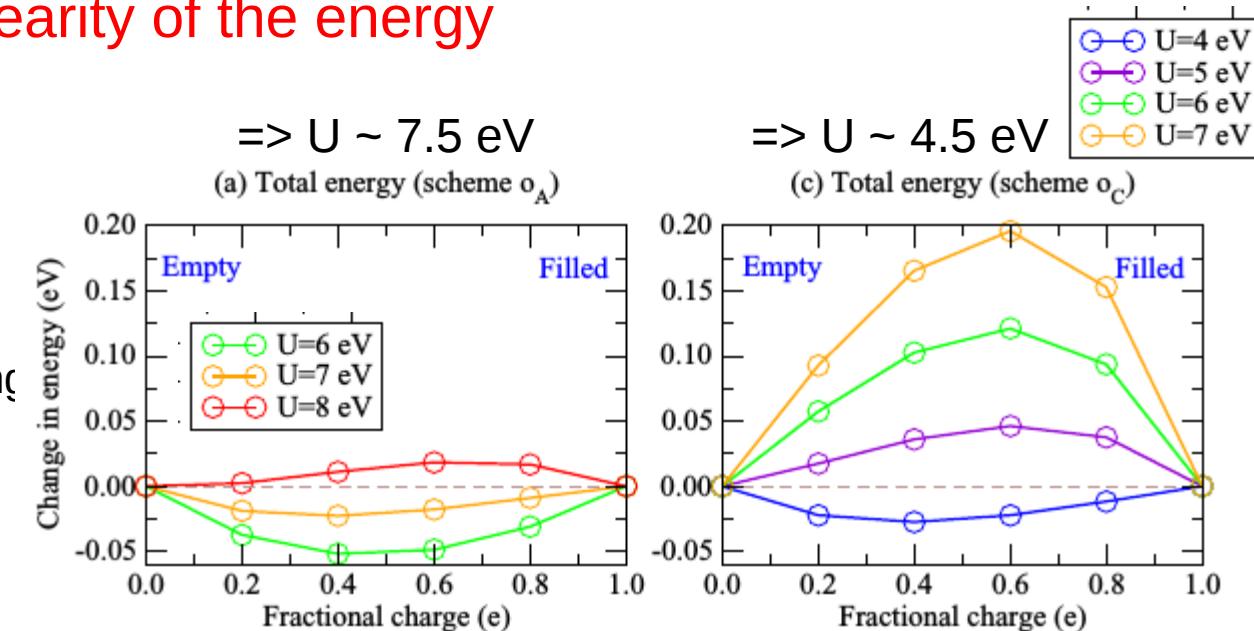
(2) Final structural optimization

- start with geometry obtained at the end of (1)
- relax previous constraint by imposing occ matrices only at beginning of 1st ionic step

```
usedmatpu 30
nstep 100
dmatpawu
...
#atom A
0.8 0.0 0.0
0.0 0.8 0.0
0.0 0.0 0.0 #hole (y,z,x)
...
- terminate structural optimization
ionmov 2 ntime 100
tolmxf 1.0d-4 #fully optimized
```

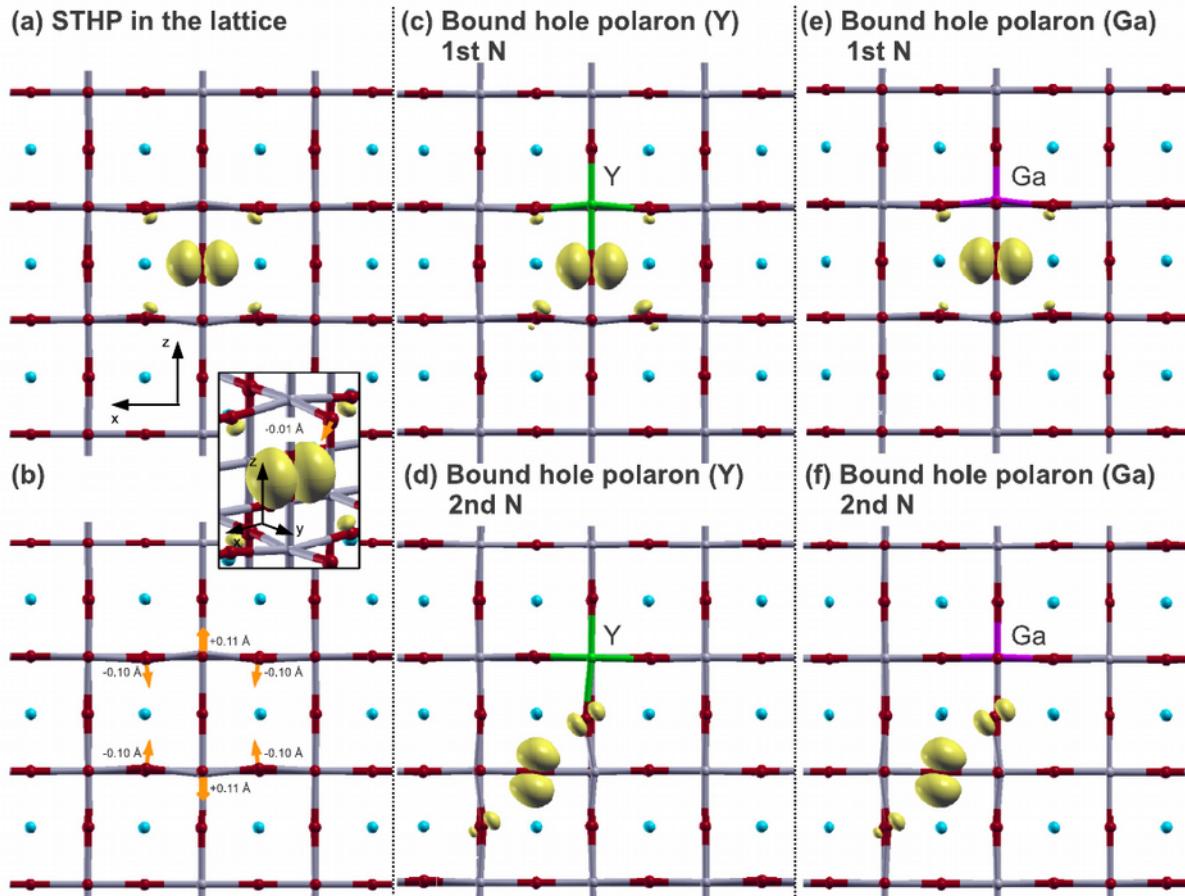
II – Computation of a self-trapped small polaron using DFT

- Choice of U to simulate small polarons
 - U generally chosen to reproduce bulk properties (bandgap), or directly calculated
 - Small polarons: U can be chosen to cancel self-interaction error
- Idea: polaron = additional charge $q=\pm 1$, how does the energy vary when going continuously from 0 to q ?
- The energy varies linearly as a function of the number of electrons between two consecutive integer values = **piecewise linearity of the energy**
- In practise:
 - freeze a polaronic configuration
 - Compute total energy by varying *charge* from 0 to $q=\pm 1$ by fractional value
 - Plot energy change w/r to linearity as a function of fractional charge
 - Choose U to be as close as possible to linearity (change)



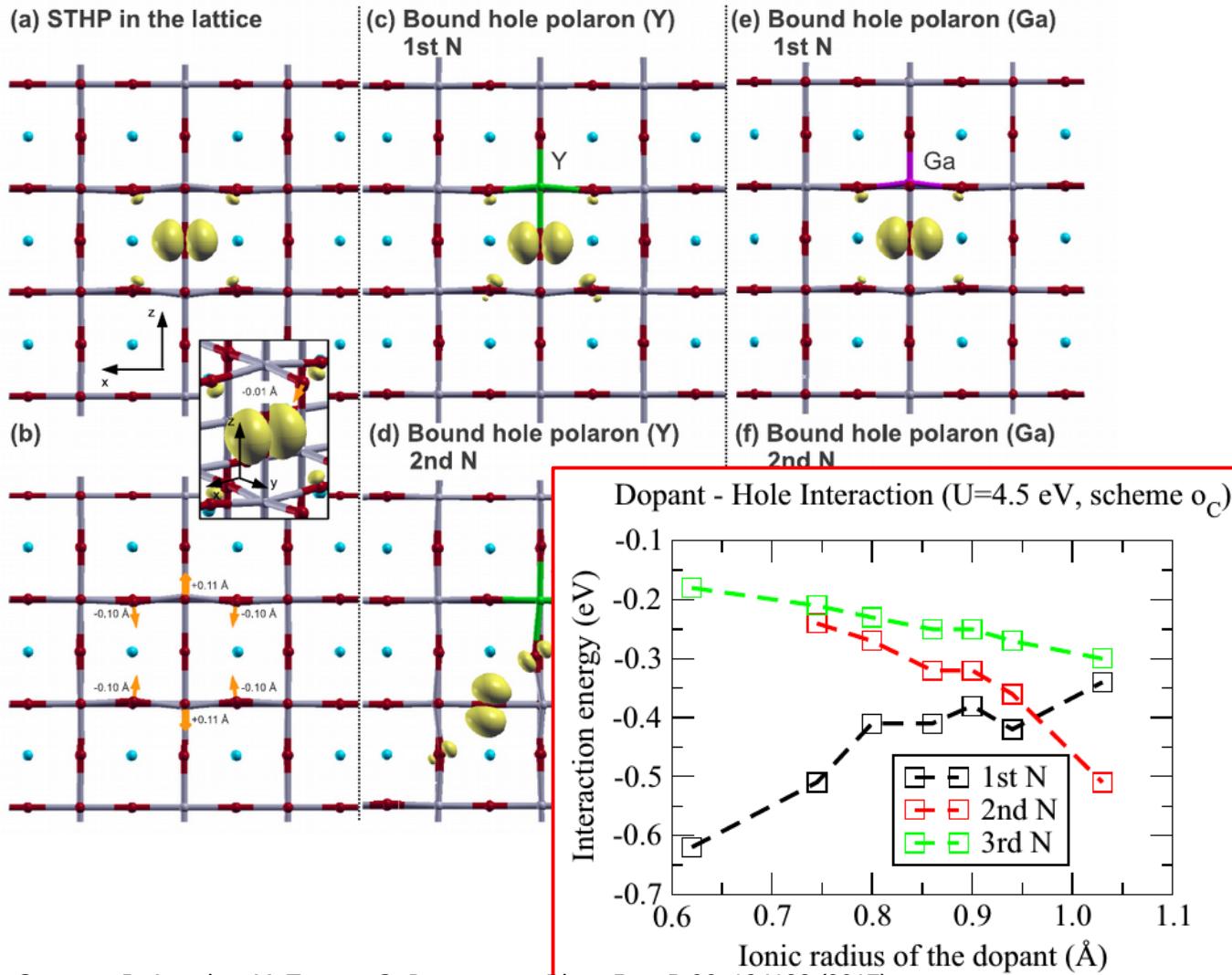
II – Computation of a self-trapped small polaron using DFT

Example 1: Hole polaron in BaSnO_3



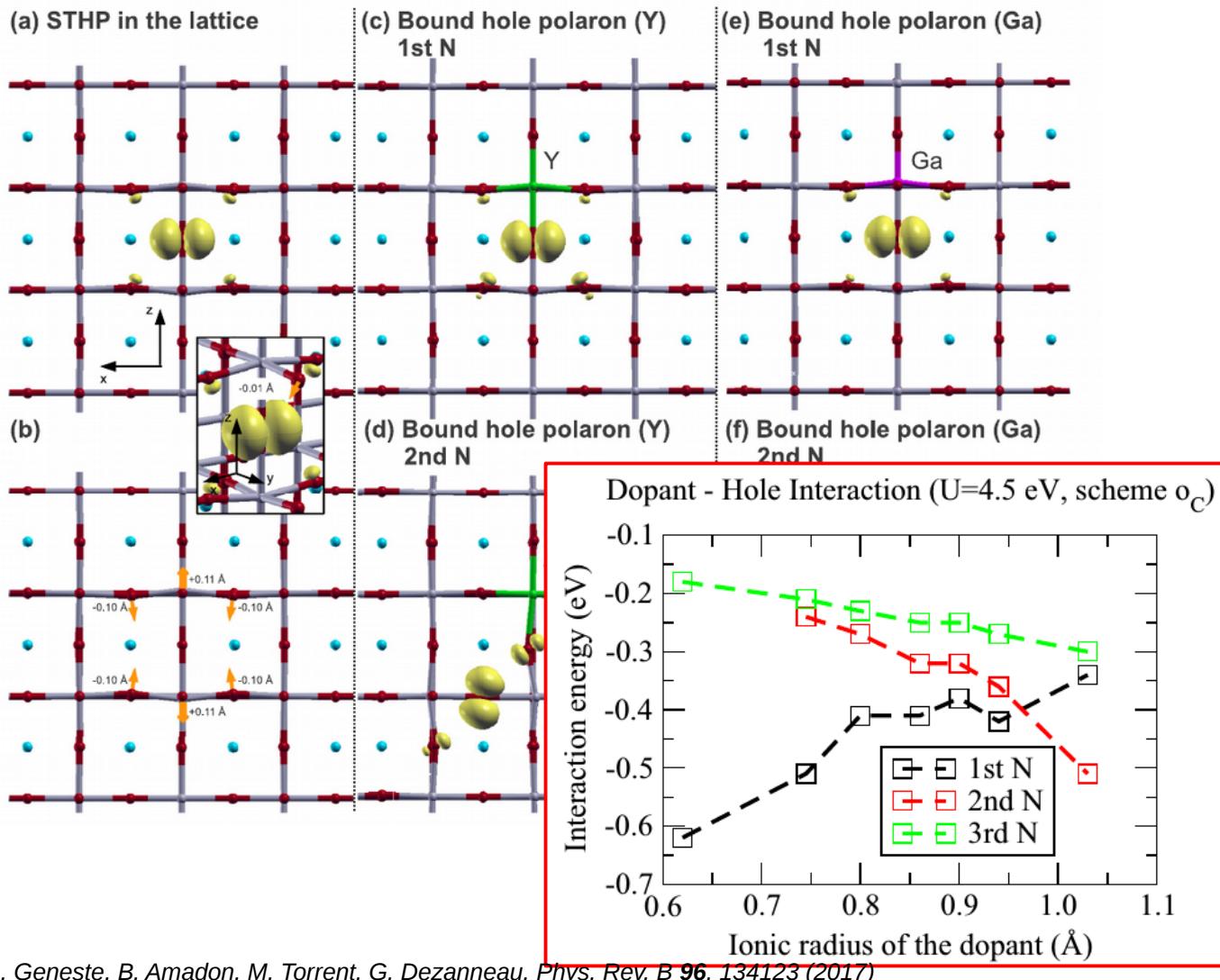
II – Computation of a self-trapped small polaron using DFT

Example 1: Hole polaron in BaSnO_3



II – Computation of a self-trapped small polaron using DFT

Example 1: Hole polaron in BaSnO_3



Example 2: electron polaron in BiFeO_3

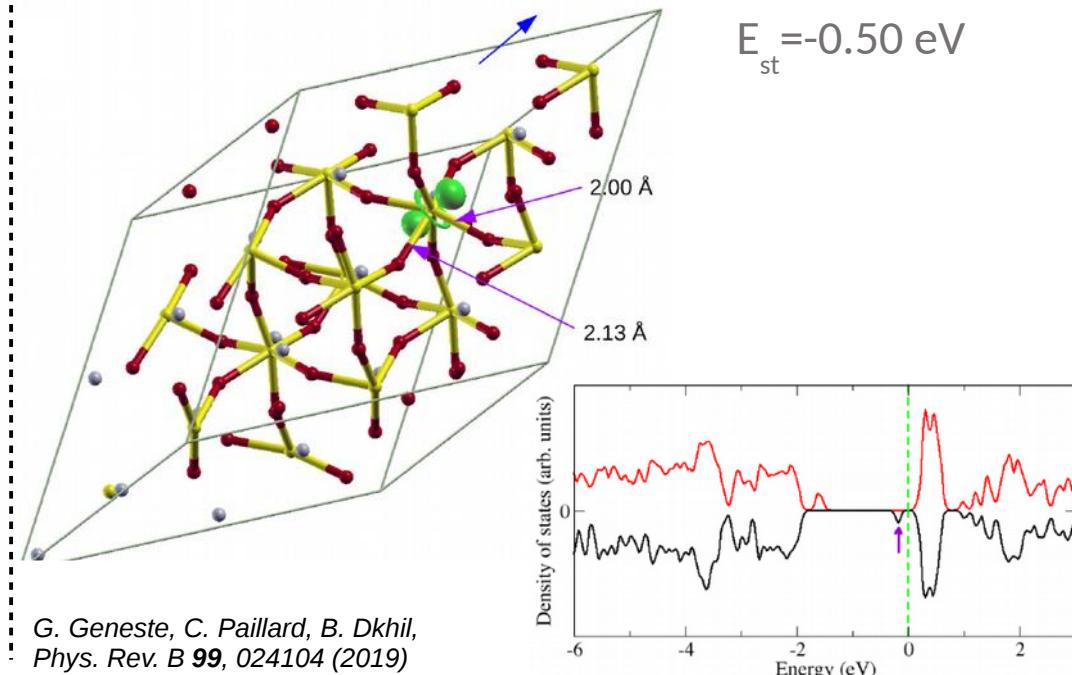
Localizes on Fe, 3d orbital $\text{Fe}^{3+} + e^- \rightarrow \text{Fe}^{2+}$

Fe^{3+} : $3d^5$ high-spin \Rightarrow 5 possibilities, which one ?

Risk of being blocked in metastable state (DFT +U)

\Rightarrow Exploration by two-step-procedure of the 5 possibilities

The most stable is retained



III – Small polaron hopping

- Small polaron hopping = **thermally activated** process
Thermal agitation of **atoms**, since the electron/hole remains in its GS !
- Transfer: **tunneling process** in specific configurations = **COINCIDENCE**
- Two limits
 - If tunneling time << coincidence timescale: **ADIABATIC** transfer
The adiabatic approximation remains valid at coincidence.
 - If tunneling time >> coincidence timescale: **NON-ADIABATIC** transfer
- Hopping can be computed by NEB or String Method
with assumption that the adiabatic approximation is valid all along the process
- ABINIT DFT+U: occupation matrices can be constrained
 - dmatpawu_1img dmatpawu_lastimg
 - ...
 - ...

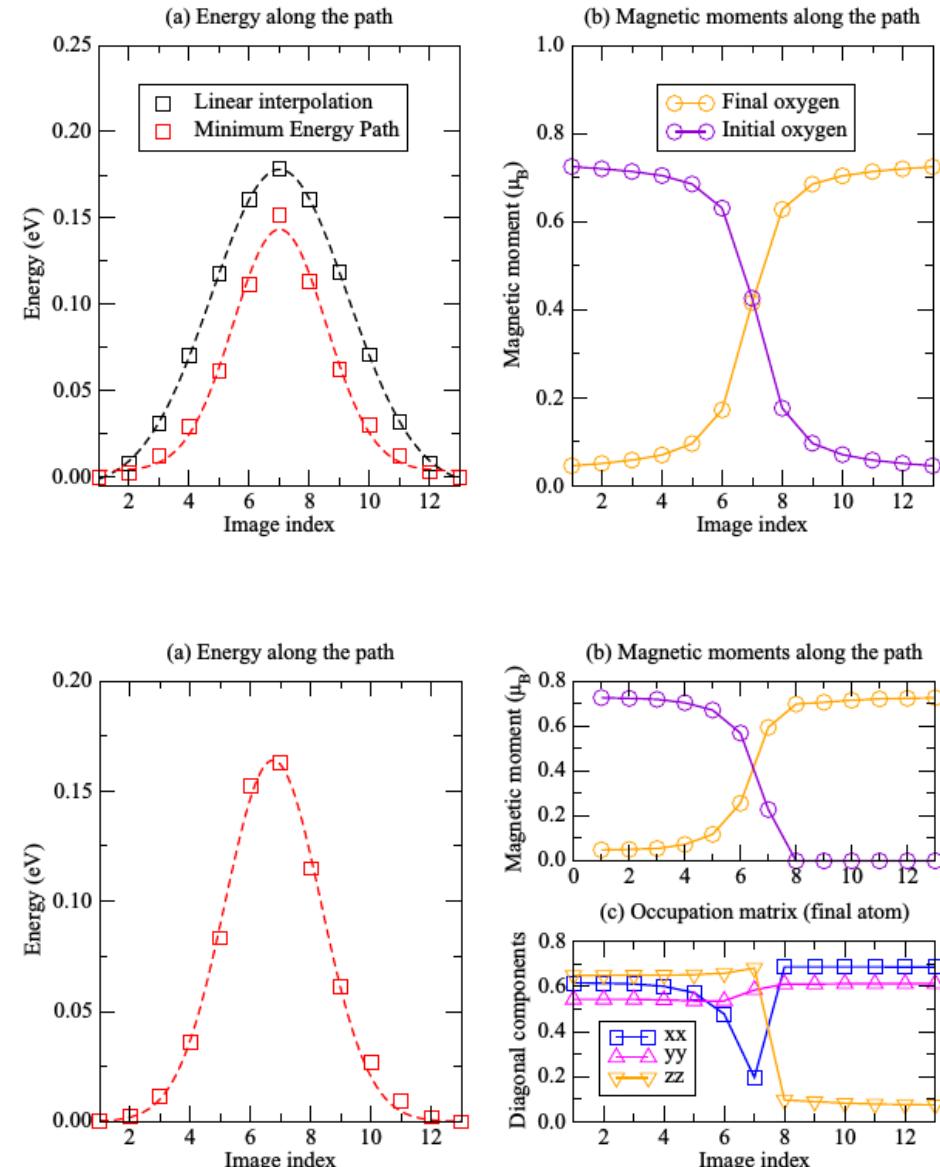
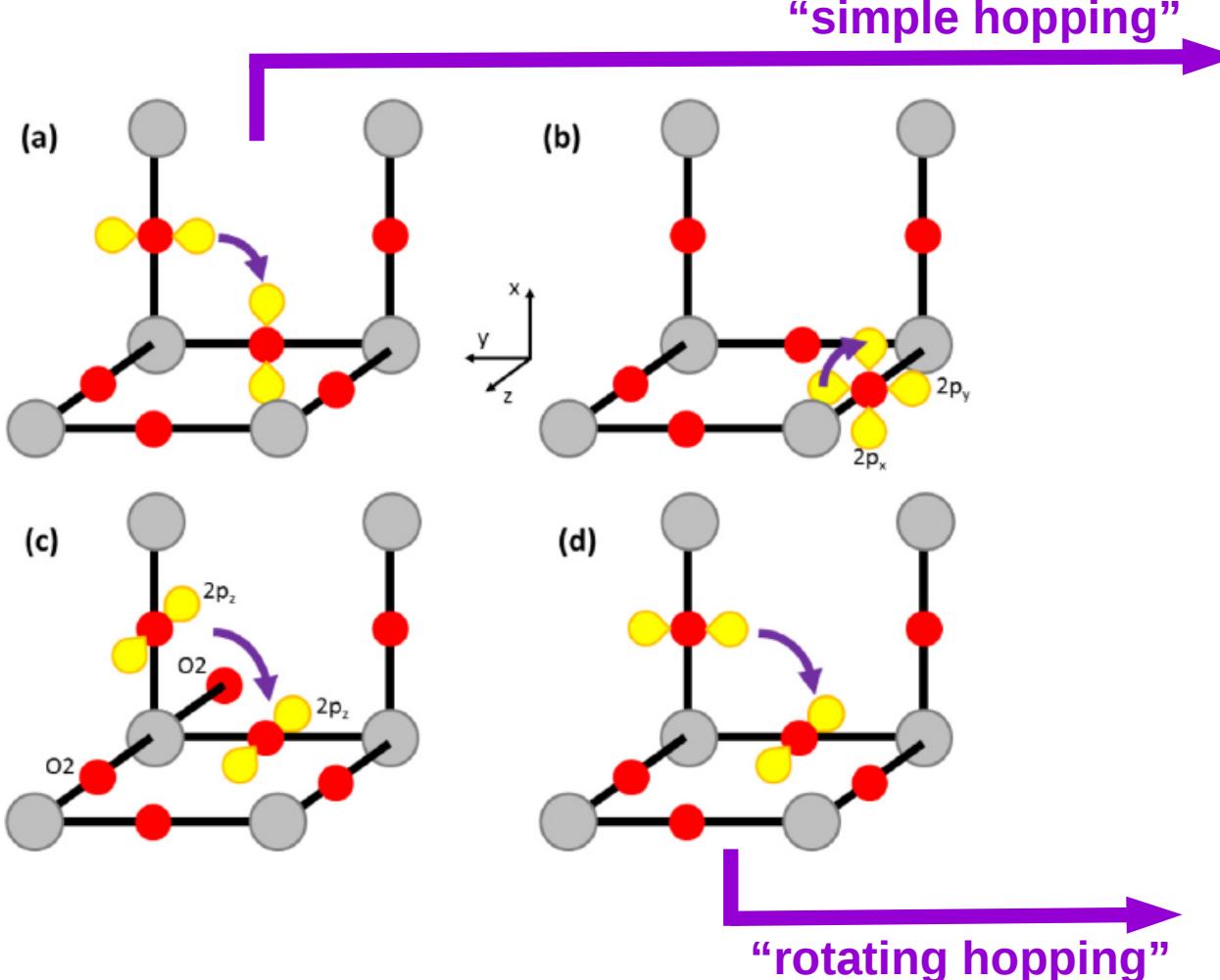


Imposes along the path a linear interpolation
between occupation matrices of 1st and last image

III – Small polaron hopping

Ex: hole polaron hopping in BaSnO₃

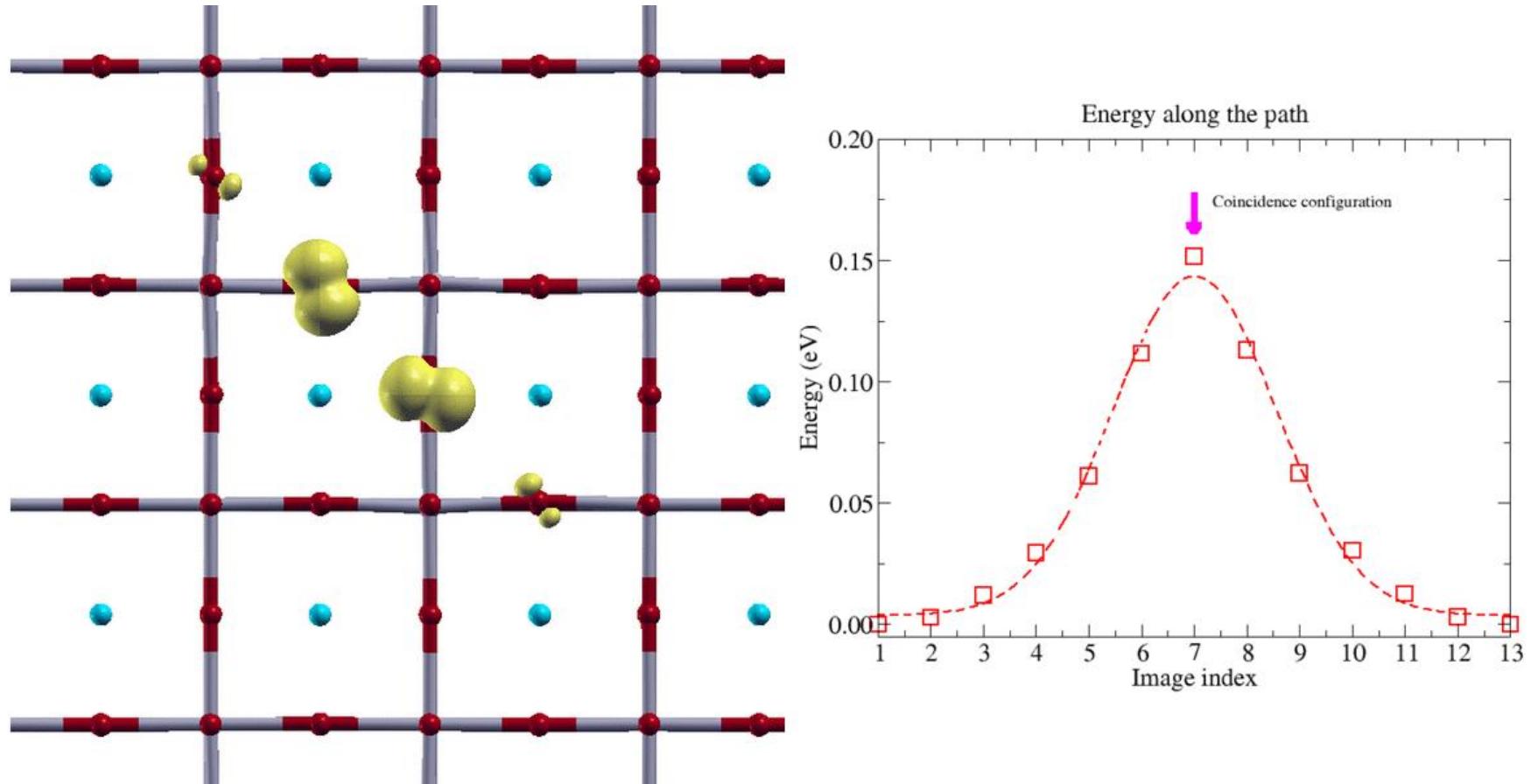
Hole = oxygen-type / String Method



G. Geneste, B. Amadon, M. Torrent, G. Dezanneau, Phys. Rev. B **96**, 134123 (2017)

III – Small polaron hopping

“Simple hopping” mechanism:



G. Geneste, B. Amadon, M. Torrent, G. Dezanneau, Phys. Rev. B **96**, 134123 (2017)

- ABINIT offers functionalities to simulate efficiently small polarons:
Occupation matrices of correlated orbitals (DFT+U)
- Allows to simulate polaron on given atom, in given orbital, with a systematic procedure
- Allows to find the most stable quantum state for a polaron
- Allows to compute hopping path



Acknowledgments

B. Amadon, G. Dezanneau, C. Paillard, B. Dkhil



Thank you for your attention